

L Number	Hits	Search Text	DB	Time stamp
-	7	US-4623805-\$.DID. OR US-4755704-\$.DID. OR US-4338569-\$.DID. OR US-4604582-\$.DID. OR US-4637018-\$.DID. OR US-5272729-\$.DID. OR US-4330852-\$.DID.	USPAT; US-PGPUB; EPO; JPO	2004/10/19 16:09
-	0	method and (source same bias same region) and (drain same bias same region) and (frequency same domain same erase same control same gate)	USPAT; US-PGPUB; EPO; JPO	2004/10/19 16:10
-	0	method and (source same bias same region) and (drain same bias same region) and (domain same erase same control same gate)	USPAT; US-PGPUB; EPO; JPO	2004/10/19 16:11
-	1042129	memory	USPAT; US-PGPUB; EPO; JPO	2004/10/19 16:11
-	0	(erasing same ((non adj volatile) or nonvolatile) same electrically) and (source same voltage) and (drain same voltage) and (floating same gate) and (frequency same domain same voltage same cell same erase)	USPAT; US-PGPUB; EPO; JPO	2004/10/19 16:13
-	26	(erasing same ((non adj volatile) or nonvolatile) same electrically) and (source same voltage) and (drain same voltage) and (floating same gate) and (frequency same voltage same cell same erase)	USPAT; US-PGPUB; EPO; JPO	2004/10/20 11:20
-	43	(erasing same ((non adj volatile) or nonvolatile)) and (source same voltage) and (drain same voltage) and (floating same gate) and (frequency same voltage same cell same erase)	USPAT; US-PGPUB; EPO; JPO	2004/10/20 16:29
-	58	((non adj volatile) or nonvolatile)) and (source same voltage) and (drain same voltage) and (floating same gate) and (frequency same voltage same cell same erase)	USPAT; US-PGPUB; EPO; JPO	2004/10/20 16:29